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V60DM120C-M3, V60DM120CHM3

Vishay General Semiconductor

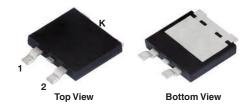
HALOGEN

FREE

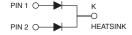
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS[®] eSMP[®] Series TO-263AC (SMPD)



V60DM120C



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V_{RRM}	120 V			
I _{FSM}	320 A			
V _F at I _F = 30 A (T _A = 125 °C)	0.70 V			
T _J max.	175 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- · Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

MECHANICAL DATA

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	120	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	^	
	per diode		30	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	320	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	

V60DM120C-M3, V60DM120CHM3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.51	-	V	
	I _F = 15 A			0.68	-		
	I _F = 30 A			0.87	0.97		
	I _F = 5 A	T _A = 125 °C		0.43	-		
	I _F = 15 A			0.58	-		
	I _F = 30 A			0.69	0.77		
Reverse current at rated V _R per diode	V _R = 90 V	T _A = 25 °C		0.01	-		
		T _A = 125 °C	I _R ⁽²⁾	5	-	mA	
	V _D = 120 V	T _A = 25 °C	'R (-)	-	0.7	IIIA	
		T _A = 125 °C		10	35		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Typical thermal resistance	per device	$R_{ heta JC}$	0.95	°C/W	
	per device	R _{0JA} (1)(2)	45	C/VV	

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V60DM120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V60DM120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

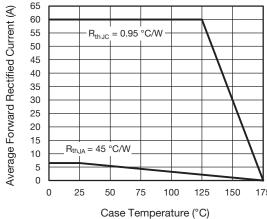


Fig. 1 - Forward Current Derating Curve

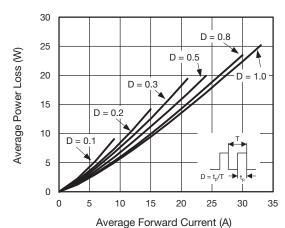


Fig. 2 - Forward Power Loss Characteristics Per Diode



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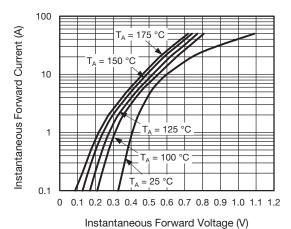
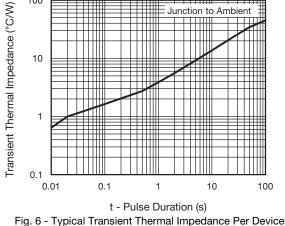


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



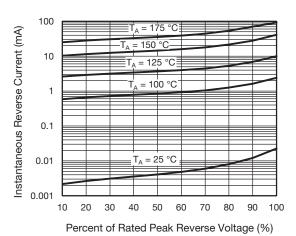


Fig. 4 - Typical Reverse Characteristics Per Diode

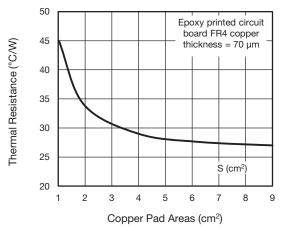


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

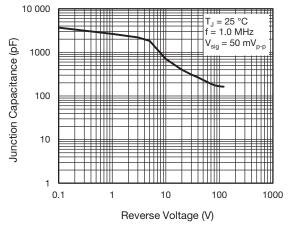
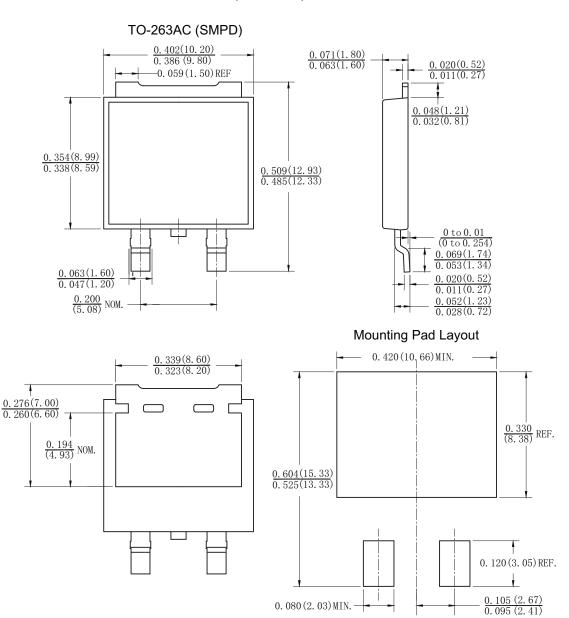


Fig. 5 - Typical Junction Capacitance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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